

III/42 Physics of Covered Solid Surfaces

A: Adsorbed Layers on Surfaces

Part 1: Adsorption on Surfaces and Surface Diffusion of Adsorbates

| | | |
|-----------|---|------------------------|
| 1 | Introduction to physical and chemical properties of adlayer/substrate systems (H.P. BONZEL)..... | 1 |
| 1.1 | General background | 1 |
| 1.2 | Surface thermodynamics | 3 |
| 1.3 | Kinetics of adsorption/desorption and adsorption isotherms | 9 |
| 1.3.1 | Thermal rates of adsorption/desorption | 9 |
| 1.3.2 | Isotherms..... | 15 |
| 1.3.3 | Non-thermal desorption..... | 16 |
| 1.4 | Physical and chemical properties of adsorbed species | 17 |
| 1.4.1 | Sticking coefficient | 17 |
| 1.4.2 | Heat of adsorption | 18 |
| 1.4.3 | Orientation of adsorbed molecules | 19 |
| 1.4.4 | Surface diffusion coefficients | 22 |
| 1.4.5 | Long-range order | 25 |
| 1.4.6 | Vibrational frequencies | 27 |
| 1.4.7 | Structure and adsorption site | 30 |
| 1.4.8 | Molecular orbital energies, dispersion and 2d band structure | 32 |
| 1.4.9 | Core level binding energies | 34 |
| 1.4.10 | Two-dimensional phase diagrams and order-disorder transitions..... | 38 |
| 1.4.11 | Chemical state | 39 |
| 1.4.12 | Influence of surface structural defects | 40 |
| 1.4.13 | Influence of chemical surface additives ("promoters") | 42 |
| 1.5 | Adsorbate-induced changes of substrate properties..... | 44 |
| 1.5.1 | Changes of structure: surface relaxation and surface reconstruction | 44 |
| 1.5.2 | Changes of electron work function | 46 |
| 1.5.3 | Electron binding energy changes, core and valence levels | 48 |
| 1.5.4 | Changes of surface free energy and surface stress | 50 |
| 1.5.5 | Changes of surface phonon dispersion | 53 |
| 1.5.6 | Changes of surface optical properties | 54 |
| | References for 1 | 59 |
| 2 | Characterization of adsorbate overlayers: measuring techniques (CH. WÖLL) | see subvolume III/42A2 |
| 3 | Data: Adsorbate properties | 67 |
| 3.1 | Adsorption of noble gases..... | 67 |
| 3.1.1 | Noble gases on metals and semiconductors (P. ZEPPENFELD) | 67 |
| 3.1.1.1 | Introduction | 67 |
| 3.1.1.1.1 | General remarks | 67 |
| 3.1.1.1.2 | The interaction of noble gases at surfaces | 67 |
| 3.1.1.1.3 | Sticking and accommodation..... | 68 |
| 3.1.1.1.4 | Adsorption energies | 69 |
| 3.1.1.1.5 | Desorption energies and desorption kinetics | 70 |
| 3.1.1.1.6 | Structure and phase diagram | 70 |

| | | |
|-------------|---|-----|
| 3.1.1.1.7 | Adsorption site | 71 |
| 3.1.1.1.8 | Electronic structure | 72 |
| 3.1.1.1.9 | Diffusion kinetics | 73 |
| 3.1.1.1.10 | Lattice dynamics | 73 |
| 3.1.1.2 | Data | 75 |
| 3.1.1.2.1 | Sticking coefficients of the noble gases | 76 |
| 3.1.1.2.2 | Binding energies, thermodynamic quantities and phase diagrams | 77 |
| 3.1.1.2.3 | Monolayer structures and phase diagrams | 82 |
| 3.1.1.2.4 | Electronic structure | 87 |
| 3.1.1.2.5 | Surface diffusion coefficients | 94 |
| 3.1.1.2.6 | Vibration frequencies and phonon dispersion | 95 |
| | Figures for 3.1.1 | 96 |
| | References for 3.1.1 | 111 |
| 3.1.2 | Noble gases on graphite, lamellar halides, MgO and NaCl (M. BIENFAIT) | 117 |
| 3.1.2.1 | Thermodynamics | 117 |
| 3.1.2.1.1 | Rare gases adsorbed on graphite (0001) | 117 |
| 3.1.2.1.1.1 | Xenon on graphite | 117 |
| 3.1.2.1.1.2 | Krypton on graphite | 117 |
| 3.1.2.1.1.3 | Argon on graphite | 118 |
| 3.1.2.1.1.4 | Neon on graphite | 118 |
| 3.1.2.1.1.5 | Rare gas mixtures on graphite | 118 |
| 3.1.2.1.1.6 | Helium on graphite | 118 |
| 3.1.2.1.2 | Rare gases on BN | 118 |
| 3.1.2.1.3 | Rare gases on lamellar halide surfaces | 118 |
| 3.1.2.1.4 | Rare gases on MgO(100) and NaCl(100) | 119 |
| 3.1.2.2 | Structure | 119 |
| 3.1.2.2.1 | Xenon on graphite | 119 |
| 3.1.2.2.2 | Krypton on graphite | 119 |
| 3.1.2.2.3 | Argon on graphite | 119 |
| 3.1.2.2.4 | Neon on graphite | 120 |
| 3.1.2.2.5 | Rare gas mixtures on graphite | 120 |
| 3.1.2.2.6 | Rare gas on lamellar halides | 120 |
| 3.1.2.2.7 | Rare gases on MgO(100) and NaCl(100) | 120 |
| 3.1.2.3 | Influence of structural defects | 120 |
| 3.1.2.3.1 | Thermodynamics and phase transitions | 120 |
| 3.1.2.3.2 | Structure | 120 |
| 3.1.2.4 | Vibrations | 121 |
| 3.1.2.5 | Kinetics of adsorption and desorption | 121 |
| | Figures for 3.1.2 | 122 |
| | References for 3.1.2 | 128 |
| 3.2 | Adsorption of alkali metals | 131 |
| 3.2.1 | Alkali metals on metals (R.D. DIEHL, R. McGRATH) | 131 |
| 3.2.1.1 | Introduction | 131 |
| 3.2.1.2 | Adsorbed alkali metals: Data | 132 |
| 3.2.1.2.1 | Adsorption bonds | 132 |
| 3.2.1.2.2 | Work function changes | 133 |
| 3.2.1.2.3 | Electronic structure of adatoms | 138 |
| 3.2.1.2.4 | Heats of adsorption/desorption | 140 |
| 3.2.1.2.5 | Adatom vibrational frequencies | 141 |
| 3.2.1.2.6 | Adsorption sites and bond lengths (commensurate structures) | 143 |
| 3.2.1.2.7 | Incommensurate overlayer rotations | 147 |
| 3.2.1.2.8 | Monolayer saturation lattice parameters | 149 |
| 3.2.1.2.9 | Condensation transition parameters | 150 |

| | | |
|------------|---|-----|
| 3.2.1.2.10 | Two-dimensional phase diagrams | 152 |
| 3.2.1.2.11 | Adsorbate substrate intermixing | 154 |
| | Figures for 3.2.1 | 157 |
| | References for 3.2.1 | 169 |
| 3.2.2 | Alkali metals on semiconductors (E.G. MICHEL, R. MIRANDA) | 179 |
| 3.2.2.1 | Introduction | 179 |
| 3.2.2.1.1 | Historical layout and general background | 179 |
| 3.2.2.1.2 | Alkali metal/semiconductor interfaces | 180 |
| 3.2.2.1.3 | Experimental techniques | 180 |
| 3.2.2.2 | Adsorption on covalent semiconductors: physical and chemical properties | 180 |
| 3.2.2.2.1 | Adsorption site, structure and long range order | 181 |
| 3.2.2.2.2 | Adsorption energy and saturation coverage | 185 |
| 3.2.2.2.3 | Metallization and electronic structure | 186 |
| 3.2.2.2.4 | Overlayer plasmons and electron excitations | 189 |
| 3.2.2.2.5 | Core level binding energies and components | 189 |
| 3.2.2.2.6 | Chemical state and nature of the bond | 191 |
| 3.2.2.3 | Adsorption on III-V semiconductors: physical and chemical properties | 193 |
| 3.2.2.3.1 | Long range order, structure and adsorption site | 193 |
| 3.2.2.3.2 | Metallization and electronic structure | 193 |
| | Figures for 3.2.2 | 195 |
| | References for 3.2.2 | 210 |
| 3.3 | Adsorption of metals | 217 |
| 3.3.1 | Metals on metals (H. BRUNE) | 217 |
| 3.3.1.1 | Introduction | 217 |
| 3.3.1.2 | Adsorption energies | 218 |
| 3.3.1.3 | Atom condensation | 225 |
| 3.3.1.3.1 | Transient mobility | 225 |
| 3.3.1.3.2 | Neighbor-driven mobility | 226 |
| 3.3.1.4 | Adsorbate – adsorbate interactions | 227 |
| 3.3.1.4.1 | Dimer bond energies | 228 |
| 3.3.1.4.2 | Long range interactions | 230 |
| 3.3.1.5 | Overlayer structure | 231 |
| | Acknowledgements | 243 |
| | Figures for 3.3.1 | 244 |
| | References for 3.3.1 | 251 |
| 3.3.2 | Metals on semiconductors (V.G. LIFSHITS, K.OURA, A.A. SARANIN, A.V. ZOTOV) | 259 |
| | List of Abbreviations | 259 |
| 3.3.2.1 | Introduction | 260 |
| 3.3.2.1.1 | Outline | 260 |
| 3.3.2.1.2 | Metal adsorption and surface phase formation | 261 |
| 3.3.2.1.3 | Notations for surface structures and adsorption sites | 263 |
| 3.3.2.1.4 | Preparation | 265 |
| 3.3.2.1.5 | Techniques of surface characterization | 267 |
| 3.3.2.2 | List of structures | 268 |
| 3.3.2.3 | Metallic adsorbates on silicon | 284 |
| 3.3.2.3.1 | Ag (Silver) on Si | 284 |
| 3.3.2.3.2 | Al (Aluminum) on Si | 292 |
| 3.3.2.3.3 | As (Arsenic) on Si | 299 |
| 3.3.2.3.4 | Au (Gold) on Si | 303 |
| 3.3.2.3.5 | Ba (Barium) on Si | 310 |
| 3.3.2.3.6 | Bi (Bismuth) on Si | 311 |
| 3.3.2.3.7 | Ca (Calcium) on Si | 316 |

| | | |
|-------------|--|------------------------|
| 3.3.2.3.8 | Ce (Cerium) on Si | 317 |
| 3.3.2.3.9 | Co (Cobalt) on Si | 317 |
| 3.3.2.3.10 | Cu (Copper) on Si | 320 |
| 3.3.2.3.11 | Eu (Europium) on Si | 324 |
| 3.3.2.3.12 | Ga (Gallium) on Si | 324 |
| 3.3.2.3.13 | Gd (Gadolinium) on Si | 331 |
| 3.3.2.3.14 | Hg (Mercury) on Si | 331 |
| 3.3.2.3.15 | In (Indium) on Si | 332 |
| 3.3.2.3.16 | Mg (Magnesium) on Si | 340 |
| 3.3.2.3.17 | Ni (Nickel) on Si | 342 |
| 3.3.2.3.18 | Pb (Lead) on Si | 347 |
| 3.3.2.3.19 | Pd (Palladium) on Si | 353 |
| 3.3.2.3.20 | Pt (Platinum) on Si | 354 |
| 3.3.2.3.21 | Sb (Antimony) on Si | 355 |
| 3.3.2.3.22 | Sm (Samarium) on Si | 362 |
| 3.3.2.3.23 | Sn (Tin) on Si | 362 |
| 3.3.2.3.24 | Sr (Strontium) on Si | 368 |
| 3.3.2.3.25 | Te (Tellurium) on Si | 369 |
| 3.3.2.3.26 | Tl (Thallium) on Si | 370 |
| 3.3.2.3.27 | Yb (Ytterbium) on Si | 372 |
| 3.3.2.4 | Metallic adsorbates on germanium | 372 |
| 3.3.2.4.1 | Ag (Silver) on Ge | 372 |
| 3.3.2.4.2 | Al (Aluminum) on Ge | 374 |
| 3.3.2.4.3 | As (Arsenic) on Ge | 374 |
| 3.3.2.4.4 | Au (Gold) on Ge | 375 |
| 3.3.2.4.5 | Bi (Bismuth) on Ge | 376 |
| 3.3.2.4.6 | Cu (Copper) on Ge | 377 |
| 3.3.2.4.7 | Ga (Gallium) on Ge | 378 |
| 3.3.2.4.8 | In (Indium) on Ge | 381 |
| 3.3.2.4.9 | Pb (Lead) on Ge | 384 |
| 3.3.2.4.10 | Sb (Antimony) on Ge | 389 |
| 3.3.2.4.11 | Sn (Tin) on Ge | 392 |
| | References for 3.3.2 | 396 |
| 3.4 | Non-metallic atomic adsorbates on metals and semiconductors | see subvolume III/42A3 |
| 3.4.1 | Chemisorbed hydrogen on metals and semiconductors (K. CHRISTMANN) | see subvolume III/42A3 |
| 3.4.2 | C, N, O on metals and semiconductors (H. OVER) | see subvolume III/42A3 |
| 3.4.3 | Halogens on metals and semiconductors (E.I. ALTMAN) | 421 |
| 3.4.3.1 | Introduction | 421 |
| 3.4.3.2 | General features of halogen adsorption | 422 |
| 3.4.3.3 | Halogen adsorption on metal surfaces | 423 |
| 3.4.3.3.1 | FCC transition metals | 423 |
| 3.4.3.3.1.1 | FCC (100) surfaces | 423 |
| 3.4.3.3.1.2 | FCC (111) surfaces | 426 |
| 3.4.3.3.1.3 | FCC (110) surfaces | 429 |
| 3.4.3.4 | BCC transition metals | 431 |
| 3.4.3.4.1 | BCC (100) surfaces | 432 |
| 3.4.3.4.2 | BCC (110) surfaces | 434 |
| 3.4.3.4.3 | BCC (111) surfaces | 437 |
| 3.4.3.5 | HCP transition metals | 438 |
| 3.4.3.6 | Semiconductor surfaces | 439 |
| 3.4.3.6.1 | Diamond cubic semiconductors | 439 |

| | | |
|-------------|--|------------------------|
| 3.4.3.6.1.1 | Diamond cubic (100) surfaces | 439 |
| 3.4.3.6.1.2 | Diamond cubic (111) surfaces | 440 |
| 3.4.3.6.2 | Zinc blende III-V semiconductor surfaces | 441 |
| 3.4.3.6.2.1 | Zinc blende (110) surfaces | 441 |
| 3.4.3.6.2.2 | Zinc blende (100) surfaces | 441 |
| 3.4.3.6.2.3 | Zinc blende (111) surfaces | 442 |
| | Figures for 3.4.3 | 443 |
| | References for 3.4.3 | 450 |
| 3.4.4 | P, S, As, Sb on metals and semiconductors (M. ENACHESCU, M. SALMERON) | see subvolume III/42A3 |
| 3.5 | Surface segregation of atomic species (non-metal on metal) (H.-J. GRABKE, CH. UEBING, H. VIEFHAUS) | see subvolume III/42A3 |
| 3.6 | Molecules on graphite, BN, MgO (except noble gases) (H. WIECHERT, J. SUZANNE) | see subvolume III/42A3 |
| 3.7 | Molecular diatomic adsorbates on metals and semiconductors | see subvolume III/42A3 |
| 3.7.1 | CO and N ₂ on metals (A. FÖHLISCH, A. NILSSON, H.P. BONZEL) | see subvolume III/42A3 |
| 3.7.2 | NO, CN, O ₂ on metals (W.A. BROWN) | see subvolume III/42A3 |
| 3.7.3 | Diatomic molecules on alloys (B. E. NIEUWENHUYS) | see subvolume III/42A3 |
| 3.7.4 | Diatomic molecules on semiconductors (K. HORN) | see subvolume III/42A3 |
| 3.8 | Molecular polyatomic adsorbates on metals and semiconductors | see subvolume III/42A3 |
| 3.8.1 | H ₂ O and OH on metals (G. PIRUG) | see subvolume III/42A3 |
| 3.8.2 | H ₂ O and OH on semiconductors (W. JAEGERMANN, T. MAYER) | see subvolume III/42A3 |
| 3.8.3 | NH ₃ and PF ₃ on metals and semiconductors (E. HASSELBRINK) | see subvolume III/42A3 |
| 3.8.4 | CO ₂ , NO ₂ , SO ₂ , OCS, N ₂ O, O ₃ (B.E. KOEL) | see subvolume III/42A3 |
| 3.8.5 | Substituted hydrocarbons on metals (W.T. TYSOE, D.R. MULLINS) | see subvolume III/42A3 |
| 3.8.6 | Linear hydrocarbons and CH ₄ on metals and semiconductors (G. SOMORJAI, G. RUPPRECHTER) | see subvolume III/42A3 |
| 3.8.7 | Cyclic hydrocarbons on metals and semiconductors (G. HELD, H.P. STEINRÜCK) | see subvolume III/42A3 |
| 3.8.8 | Oxygenated hydrocarbons on metals and semiconductors (J. VOHS) | see subvolume III/42A3 |
| 3.8.9 | Halogen-substituted hydrocarbons on metals and semiconductors (J. FIEBERG, J.W. WHITE) | see subvolume III/42A3 |
| 3.8.10 | Polyatomic chain-like hydrocarbons on metals and semiconductors (M. GRUNZE) | see subvolume III/42A3 |
| 3.8.11 | Large aromatic adsorbates on metals and semiconductors (M. SOKOŁOWSKI, E. UMBACH) | see subvolume III/42A3 |
| 3.9 | Adsorption on oxides (H. KUHLENBECK, H.J. FREUND) | see subvolume III/42A3 |
| 3.10 | Adsorption on alkali halides (J. HEIDBERG) | see subvolume III/42A3 |
| 3.11 | Surface diffusion on metals, semiconductors, and insulators (E.G. SEEBAUER, M.Y.L. JUNG) | 455 |
| 3.11.1 | Introduction | 455 |

| | | |
|--------------|---|------------------------|
| 3.11.1.1 | General remarks | 455 |
| 3.11.1.2 | Intrinsic and mass transfer diffusion | 456 |
| 3.11.2 | Methodology | 458 |
| 3.11.2.1 | Experimental techniques | 458 |
| 3.11.2.1.1 | Single-atom imaging | 458 |
| 3.11.2.1.2 | Field emission | 459 |
| 3.11.2.1.3 | Electron diffraction | 459 |
| 3.11.2.1.4 | Chemical state relaxation | 460 |
| 3.11.2.1.5 | Spin axis relaxation | 460 |
| 3.11.2.1.6 | Profile evolution | 461 |
| 3.11.2.1.7 | Capillarity-driven effects | 463 |
| 3.11.2.1.8 | Island growth | 463 |
| 3.11.2.1.9 | Miscellaneous | 464 |
| 3.11.2.2 | Classification of experimental techniques | 464 |
| 3.11.2.3 | Computational techniques | 466 |
| 3.11.2.3.1 | Molecular dynamics | 466 |
| 3.11.2.3.2 | Monte Carlo method | 467 |
| 3.11.2.3.3 | <i>Ab initio</i> methods | 467 |
| 3.11.2.3.4 | Classical interatomic potentials | 467 |
| 3.11.2.3.5 | Semi-empirical potentials | 469 |
| 3.11.2.3.6 | Quantum mechanical potentials | 470 |
| 3.11.3 | Tables of data | 470 |
| 3.11.3.1 | Commentary to tables | 470 |
| 3.11.3.2 | Surface diffusion tables | 472 |
| 3.11.3.2.1 | Thermal diffusion in vacuum | 472 |
| 3.11.3.2.1.1 | Intrinsic diffusion | 472 |
| 3.11.3.2.1.2 | Mass transfer diffusion | 486 |
| 3.11.3.2.1.3 | Impurity-influenced diffusion | 489 |
| 3.11.3.2.2 | Non-thermal diffusion | 490 |
| 3.11.3.2.3 | Diffusion under liquids | 491 |
| 3.11.3.2.4 | Computational data | 492 |
| 3.11.4 | Discussion and correlations | 495 |
| 3.11.4.1 | Thermal diffusion in vacuum | 495 |
| 3.11.4.1.1 | Intrinsic diffusion on metals | 495 |
| 3.11.4.1.2 | Intrinsic diffusion on semiconductors | 496 |
| 3.11.4.1.3 | Intrinsic diffusion on insulators | 497 |
| 3.11.4.1.4 | Mass transfer diffusion on metals | 497 |
| 3.11.4.1.5 | Mass transfer diffusion on semiconductors | 498 |
| 3.11.4.1.6 | Mass transfer diffusion on insulators | 498 |
| 3.11.4.1.7 | Comparison of mass transfer diffusion on various substrates | 499 |
| 3.11.4.1.8 | Adsorbate concentration dependence | 499 |
| 3.11.4.1.9 | Impurity-influenced diffusion | 500 |
| 3.11.4.2 | Non-thermal diffusion | 500 |
| 3.11.4.2.1 | Tunneling diffusion | 500 |
| 3.11.4.2.2 | Ion- and photon-influenced diffusion | 500 |
| 3.11.4.3 | Diffusion under aqueous liquids | 501 |
| 3.11.4.4 | Computational results | 501 |
| | Acknowledgements | 501 |
| | Figures for 3.11 | 502 |
| | Special references: review articles for 3.11 | 517 |
| | References for 3.11 | 519 |
| 3.12 | Dynamics of activated adsorption | |
| | (A.C. LUNTZ) | see subvolume III/42A3 |

| | | |
|-----|---|------------------------|
| 4 | Data: adsorbate-induced changes of substrate properties | see subvolume III/42A2 |
| 4.1 | Surface structure on metals and semiconductors (M.A. VAN HOVE, P.R. WATSON, K. HERMANN) | see subvolume III/42A2 |
| 4.2 | Electron work function of metals and semiconductors (K. JAKOBI) | see subvolume III/42A2 |
| 4.3 | Electron binding energy of metals and semiconductors (R. DENECKE, N. MARTENSSON, A. NILSSON) | see subvolume III/42A3 |
| 4.4 | Surface free energy and surface stress (D. SANDER, H. BACH) | see subvolume III/42A2 |
| 4.5 | Surface phonon dispersion (M. ROCCA) | see subvolume III/42A2 |
| 4.6 | Surface optical properties (N. ESSER, W. RICHTER) | see subvolume III/42A3 |

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